

NPN POWER SILICON TRANSISTOR

Qualified per MIL-PRF-19500/394

Devices Qualified Level

2N4150 2N5237 2N5238 2N4150S 2N5237S 2N5238S JAN JANTX JANTXV

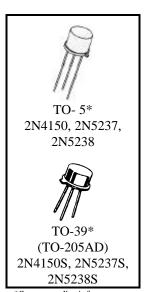
MAXIMUM RATINGS

		2N4150	2N5237	2N5238	
Ratings	Symbol	2N4150S	2N5237S	2N5238S	Unit
Collector-Emitter Voltage	V_{CEO}	70	120	170	Vdc
Collector-Base Voltage	V_{CBO}	100	150	200	Vdc
Emitter-Base Voltage	$V_{\rm EBO}$	10		Vdc	
Collector Current	I_{C}	10		Adc	
Total Power Dissipation @ $T_A = +25^0 C^{(1)}$ @ $T_C = +100^0 C^{(2)}$	P_{T}	1.0 5.0		W	
Operating & Storage Junction Temp. Range	T _J , T _{stg}		-65 to +20	0	°C

THERMAL CHARACTERISTICS

Characteristics	Symbol	Max.	Unit
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	0.020	0.00
Junction-to-Ambient	$R_{\theta JA}$	0.175	⁰ C/mW

- 1) Derate linearly @ 5.7 mW/ $^{\circ}$ C for $T_A > +25^{\circ}$ C
- 2) Derate linearly @ 50 mW/ 0 C for $T_{C} > +25^{0}$ C



*See appendix A for package outline

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}$ C unless otherwise noted)

Characteristics		Symbol	Min.	Max.	Unit
OFF CHARACTERISTICS					
Emitter-Base Breakdown Voltage					
$I_E = 10 \mu\text{Adc}$		$V_{(BR)EBO}$	7.0		Vdc
Collector-Emitter Breakdown Voltage					
$I_C = 0.1 \text{ Adc}$	2N4150, 2N4150S	$V_{(BR)CEO}$	70		
	2N5237, 2N5237S		120		Vdc
	2N5238, 2N5238S		170		
Collector-Emitter Cutoff Current					
$V_{EB} = 0.5 \text{ Vdc}, V_{CE} = 60 \text{ Vdc}$	2N4150, 2N4150S	I_{CEX}		10	μAdc
$V_{EB} = 0.5 \text{ Vdc}, V_{CE} = 110 \text{ Vdc}$	2N5237, 2N5237S			10	
$V_{EB} = 0.5 \text{ Vdc}, V_{CE} = 160 \text{ Vdc}$	2N5238, 2N5238S			10	

2N4150, 2N4150S, 2N5237, 2N5237S, 2N5238, 2N5238S JAN SERIES

ELECTRICAL CHARACTERISTICS (con't)

Characteristics		Symbol	Min.	Max.	Unit
OFF CHARACTERISTICS (con't)	<u>.</u>	•			•
Collector-Base Cutoff Current					
$V_{CE} = 60 \text{ Vdc}$	2N4150, 2N4150S	I_{CEO}		10	μAdc
$V_{CE} = 110 \text{ Vdc}$	2N5237, 2N5237S			10	
$V_{CE} = 160 \text{ Vdc}$	2N5238, 2N5238S			10	
Emitter-Base Cutoff Current					
$V_{BE} = 7.0 \text{ Vdc}$		I_{EBO}		10	μAdc
$V_{BE} = 5.0 \text{ Vdc}$				0.1	
Collector-Base Cutoff Current					
$V_{CB} = 100 \text{ Vdc}$	2N4150, 2N4150S			10	
$V_{CB} = 150 \text{ Vdc}$	2N5237, 2N5237S	I_{CBO}		10	μAdc
$V_{CB} = 200 \text{ Vdc}$	2N5238, 2N5238S			10	
$V_{CB} = 80 \text{ Vdc}$	All Types			0.1	
ON CHARACTERISTICS (3)					
Forward-Current Transfer Ratio					
$I_C = 1.0 \text{ Adc}, V_{CE} = 5.0 \text{ Vdc}$	2N4150, 2N4150S		50	200	
	2N5237, 2N5237S	h_{FE}	50	225	
	2N5238, 2N5238S		50	225	
$I_C = 5.0 \text{ Adc}, V_{CE} = 5.0 \text{ Vdc}$	All Types		40	120	
$I_C = 10 \text{ Adc}, V_{CE} = 5.0 \text{ Vdc}$	All Types		10	-	
Collector-Emitter Saturation Voltage					
$I_{\rm C} = 5.0 \text{ Adc}, I_{\rm B} = 0.5 \text{ Adc}$		$V_{CE(sat)}$		0.6	Vdc
$I_C = 10 \text{ Adc}, I_B = 1.0 \text{ Adc}$				2.5	
Base-Emitter Saturation Voltage					
$I_C = 5.0 \text{ Adc}, I_B = 0.5 \text{ Adc}$		$V_{BE(sat)}$		1.5	Vdc
$I_C = 10 \text{ Adc}, I_B = 1.0 \text{ Adc}$				25	
DYNAMIC CHARACTERISTICS					
Magnitude of Common Emitter Small-Signal S	hort-Circuit	1 1			
Forward Current Transfer Ratio		$ h_{\mathrm{fe}} $	1.5	7.5	
$I_C = 0.2 \text{ Adc}, V_{CE} = 10 \text{ Vdc}, f = 10 \text{ MHz}$					
Forward Current Transfer Ratio			4.0	1.50	
$I_C = 50 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}, f = 1.0 \text{ kHz}$	2N4150, 2N4150S		40	160	
	2N5237, 2N5237S	h_{fe}	40	160	
0 0	2N5238, 2N5238S		40	250	
Output Capacitance		C		250	"T
$V_{CB} = 10 \text{ Vdc}, I_E = 0, 100 \text{ kHz} \le f \le 1.0 \text{ MHz}$	Z	C_{obo}		350	pF
SWITCHING CHARACTERISTICS	I	t .		50	
Delay Time $V_{CC} = 20 \text{ Vdc}, V_{BB} = 5.0 \text{ Vdc}$	Σ,	t d		50	μs
Rise Time $I_C = 5.0 \text{ Adc}, I_{B1} = 0.5 \text{ Adc}$		r		500	μs
Storage Time $V_{CC} = 20 \text{ Vdc}, V_{BB} = 5.0 \text{ Vdc}$	· —	t _S		1.5	μs
Fall Time $I_C = 5.0 \text{ Adc}, I_{B1} = -I_{B2} = 0.5$	Adc	^t f		500	μs

SAFE OPERATING AREA

DC Tests

 $T_C = +25^{\circ}C$, 1 Cycle, t = 1.0 s

Test 1

 $V_{CE} = 40 \text{ Vdc}, I_{C} = 0.22 \text{ Adc}$

Test 2

 $V_{CE} = 70 \text{ Vdc}, I_C = 90 \text{ mAdc}$

Test 3

 $V_{CE} = 120 \text{ Vdc}, I_{C} = 15 \text{ mAdc}$ 2N5237, 2N5237S $V_{CE} = 170 \text{ Vdc}, I_{C} = 3.5 \text{ mAdc}$ 2N5238, 2N5238S

(3) Pulse Test: Pulse Width = $300\mu s$, Duty Cycle $\leq 2.0\%$.

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